

PIC16C63

PIC16C63 Rev. A Silicon Errata Sheet

The PIC16C63 (Rev. A) parts you have received conform functionally to the Device Data Sheet (DS30234**D**), except for the anomalies described below.

All the problems listed here will be addressed in future revisions of the PIC16C63 silicon.

1. Module: CCP (Compare Mode)

The Compare mode may not operate as expected when configuring the compare match to drive the I/O pin low (CCPxM<3:0> = 1001).

When the CCP module is changed to compare output low (CCPxM<3:0> = 1001) from any other noncompare CCP mode, the I/O pin will immediately be driven low regardless of the state of the I/O data latch. The pin will remain low when the compare match occurs (see Table 1).

However, when the CCP module is changed to compare output high (CCPxM<3:0> = 1000) from any other CCP mode, the I/O pin will immediately be driven low regardless of the state of the I/O data latch. The pin will be driven high when the compare match occurs.

TABLE 1: Compare Output Low Switching

CCD Mada	I/O	Change CCP to CCPxM<3:0> =			
CCP Mode CCPxM<3:0> =	pin State	1001	1000		
0xxx	Н	L	L		
UXXX	L	L	L		
1000	Н	Н	_		
1000	L	L	_		
1001	Н	_	L		
1001	L	_	L		
101x	Н	L	L		
IUIX	L	L	L		
11xx	Н	L	L		
1188	L	L	L		

Work Around

To have the I/O pin high until the compare match low occurs, force a compare match high to get the I/O pin into the high state, then reconfigure the compare match to force the I/O low, when the compare condition occurs.

2. Module: CCP (Compare Mode)

The special event trigger of the Compare mode may not occur if both of the following conditions exist:

- An instruction one cycle (Tcy) prior to a Timer1/ Compare register match has literal data equal to the address of a CCP register being used.⁽¹⁾
- An instruction in the same cycle as a Timer1/ Compare register match has an MSb of '0'.

The interrupt for the compare event will still be generated, but no special event trigger will occur.

Note 1: 15h(CCPR1L), 16h(CCPR1H) or 17h(CCP1CON) for CCP1; 18h(CCPR2L), 1Ch(CCPR2H) or 1Dh(CCP2CON) for CCP2.

Work Around

Use the interrupt service routine instead of using the special event trigger to reset Timer1 (and start an A/D conversion, if applicable).

3. Module: SSP Module (I²C™ mode)

If the bus is active when the I²C mode is enabled and the next 8-bits of data on the bus match the address of the device, then the SSP module will generate an acknowledge pulse.

Work Around

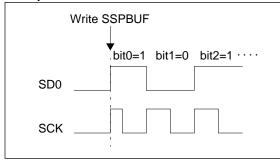
Before enabling the I²C mode, ensure that the bus is not active.

Note: As with any windowed EPROM device, please cover the window at all times, except when erasing.

4. Module: SSP (SPI Mode)

When the SPI is using Timer2/2 as the clock source, a shorter-than-expected SCK pulse may occur on the first bit of the transmitted/received data.

Example:



Work Around

To avoid producing the short pulse, turn off Timer2 and clear the TMR2 register, load the SSPBUF with the data to transmit, and then turn Timer2 back on.

Example Code:

```
STATUS, RPO
    BSF
                       Bank 1
LOOP BTFSS SSPSTAT, BF
                       ¡Data received?
                       ;(Xmit complete?)
    GOTO LOOP
                      ; No
    BCF STATUS, RPO ; Bank 0
    MOVF SSPBUF, W ;W = SSPBUF
    MOVWF RXDATA
                       ;Save in user RAM
         TXDATA, W
                       ;W = TXDATA
    MOVF
         T2CON, TMR2ON ;Timer2 off
    BCF
    CLR TMR2
                       Clear Timer?
    MOVWF SSPBUF
                       ;Xmit New data
    BSF T2CON, TMR2ON ; Timer2 on
```

5. Module: Timer0

The TMR0 register may increment when the WDT postscaler is switched to the Timer0 prescaler. If TMR0 = FFh, this will cause TMR0 to overflow (setting T0IF).

Work Around

Follow the following sequence:

- a) Read the 8-bit TMR0 register into the W register
- b) Clear the TMR0 register
- c) Assign WDT postscaler to Timer0
- d) Write W register to TMR0

6. Module: Timer1

The Timer1 value may unexpectedly increment if either the TMR1H or the TMR1L register is written. If Timer1 is ON, then turned OFF, performing any write instruction with TMR1H as the destination may cause TMR1L to increment.

Example 1:

```
BSF T1CON, TMR1ON : BCF T1CON, TMR1ON MOVF TMR1H, 1
```

TMR1 value before MOVF instruction:

TMR1H:TMR1L = 3F:00

TMR1 value after MOVF instruction:

TMR1H:TMR1L = 3F:01

BSF T1CON, TMR1ON

Example 2:

```
BCF T1CON, TMR1ON
MOVF TMR1H, 1
TMR1 value before MOVF instruction:
TMR1H:TMR1L = FF:FF
TMR1 value after MOVF instruction:
TMR1H:TMR1L = FF:00
```

If Timer1 is ON, then turned OFF when TMR1H:TMR1L = xx:FF, performing any write instruction with TMR1L as the destination may cause TMR1H to increment.

Example 1:

```
BSF T1CON, TMR1ON
:
BCF T1CON, TMR1ON
CLRF TMR1L
TMR1 value before CLRF instruction:
TMR1H:TMR1L = FF:FF
TMR1 value after CLRF instruction:
TMR1H:TMR1L = 00:00
(TMR1IF is not set.)
```

Work Around

To preserve Timer1 register values:

Read Timer1 register values into "shadow" registers. Perform any write instruction(s) on the shadow registers. Write the shadow register values back into the Timer1 registers.

7. Module: USART

When the USART (SCI) is configured in asynchronous mode with the BRGH bit set, a high number of receive errors may be experienced. For asynchronous receive operations it is recommended that the USART be configured with the BRGH bit cleared.

Clarifications/Corrections to the Data Sheet:

In the Device Data Sheet (DS30234**D**), the following clarifications and corrections should be noted.

1. Module: I/O Ports

The specification for the High Voltage Open Drain I/O (The RA4 pin on most devices) cannot be met without possible long term reliability issues on that I/O pin. If a high voltage drive is required, use an external transistor that can support the required voltage.

TABLE 2: DC SPECIFICATION CHANGES FROM DATA SHEET

Param	Characteristic		New Specification			Data Sheet Specification			
No.	Sym.		Min	Тур	Max	Min	Тур	Max	Units
D150	Vod	Open-drain High Voltage	10		_	_	14	V	

2. Module: SSP (SPI Mode Timing Specificatios)

a) The SPI interface timings have been modified to the values shown in Table 3.

TABLE 3: DC SPECIFICATION CHANGES FROM DATA SHEET

Down		Characteristic		New Specification			Data Sheet Specification			
Parm No.	Sym.			Min	Тур	Max	Min	Тур	Max	Units
71	TscH	SCK input high time	Continuous	1.25Tcy + 30 ns		-	Tcy + 20 ns	_	_	ns
71A		(slave mode)	Single Byte (1)	40	_	_		N.A.		ns
72	TscL	time	Continuous	1.25Tcy + 30 ns		_	Tcy + 20 ns	_	_	ns
72A	72A		Single Byte (1)	40	_	_	N.A.		ns	
73A	Тв2в	Last clock edge of the Byte1 to 1st clock edge of the Byte2 (1)		1.5 Tcy + 40 ns	_	_	N.A.		ns	

^{*} This parameter is characterized but not tested

Note 1:Specification 73A is only required if specifications 71A and 72A are used.

3. Module: Timer1

 The operation of Timer1 needs some clarification when the timer registers are written when the TMR1ON bit is set.

The internal clock signal that is the input to the TMR1 presaler affects the incrementing of Timer1 (TMR1H:TMR1L registers and the Timer1 prescaler). When the Timer1 registers are NOT written, the Timer1 will increment on the rising edge of the TMR1 increment clock.

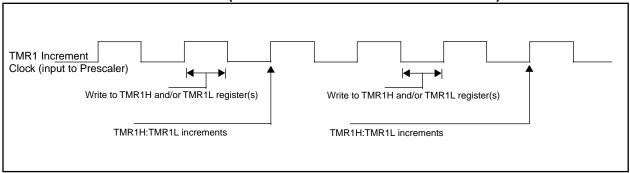
When the TMR1H and/or TMR1L registers are written while this clock is high, TMR1 will increment on the next rising edge of this clock.

When the TMR1H and/or TMR1L registers are written while this clock is low, TMR1 will not increment on the next rising edge of this clock, but must first have a falling clock and the the rising clock for TMR1 to increment.

Figure 1 shows the two cases of writes to the TMR1H and/or TMR1L registers. Due to the VIH and VIL thresholds on the oscillator/clock pins, external Timer1 oscillator components, and external clock frequency, the Timer1 increment clock may not be of a 50% duty cycle.

The TMR1 increment clock is out of phase of the T1OSO/T1CKI pin by a small propagation delay.

FIGURE 1: WRITES TO TIMER1 (EXTERNAL CLOCK / OSCILLATOR MODE)



4. Module: RC Oscillator

The table for RC oscillator frequencies in the Device Characterization section of the Data Sheet is incorrect. The correct characterization information is shown in Table 4.

FREQUENCIES CHARACTERIZATION CHANGES FROM DATA SHEET

TABLE 4: RC OSCILLATOR

		Correct Characterization Data		Current Data	Sheet Values	
Cext	Rext	Average	% Variation	Average	% Variation	
22 pF	5.1 K	3.55 MHz	± 9.63%	4.12 MHz	± 1.4%	
	10 K	1.99 MHz	1.99 MHz ± 10.53%		± 1.4%	
	100 K	221.9 KHz	± 12.10%	268 KHz	± 1.1%	
100 pF	3.3 K	1.77 MHz	± 10.67%	1.80 MHz	± 1.0%	
	5.1 K	1.22 MHz	± 10.41%	1.27 MHz	± 1.0%	
	10 K	669.4 KHz	± 10.92%	688 KHz	± 1.2%	
	100 K	71.5 KHz	± 11.21%	77.2 KHz	± 1.0%	
330 pF	3.3 K	625.1 KHz	± 10.68%	707 KHz	± 1.4%	
	5.1 K	428.5 KHz	± 10.96%	501 KHz	± 1.2%	
	10 K	231.9 KHz	± 11.32%	269 KHz	± 1.6%	
	100 K	24.4 KHz	± 12.93%	28.3 KHz	± 1.1%	

The percentage variation indicated here is part to part variation due to normal process distribution. The variation indicated is ± 3 standard deviation from the average value for Vdd = 5V



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